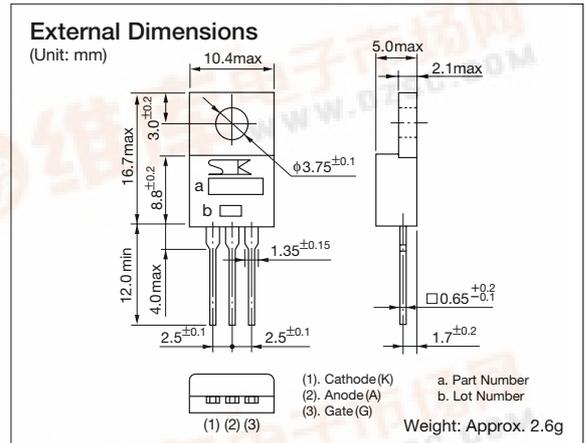


# TO-220 3A High sensitive Thyristor

## TF321M-A, TF341M-A, TF361M-A

### Features

- Repetitive peak off-state voltage:  $V_{DRM}=200, 400, 600V$
- Average on-state current:  $I_{T(AV)}=3A$
- High sensitive Gate trigger Current:  $I_{GT}=0.1mA$  max



### Absolute Maximum Ratings

Parameter	Symbol	Ratings			Unit	Conditions
		TF321M-A	TF341M-A	TF361M-A		
Repetitive peak off-state voltage	$V_{DRM}$	200	400	600	V	$T_j = -40$ to $+125^{\circ}C$ , $R_{GK}=1k\Omega$
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	V	
Non-repetitive peak off-state voltage	$V_{DSM}$	300	500	700	V	
Non-repetitive peak reverse voltage	$V_{RSM}$	300	500	700	V	
Average on-state current	$I_{T(AV)}$	3.0			A	50Hz Half-cycle sinewave, Continuous current, $T_c=87^{\circ}C$
RMS on-state current	$I_{T(RMS)}$	4.7			A	
Surge on-state current	$I_{TSM}$	60			A	50Hz Half-cycle sinewave, Single shot, Non-repetitive, $T_j=125^{\circ}C$
Peak forward gate current	$I_{FGM}$	2.0			A	$f \geq 50Hz$ , duty $\leq 10\%$
Peak forward gate voltage	$V_{FGM}$	10			V	
Peak reverse gate voltage	$V_{RGM}$	5.0			V	$f \geq 50Hz$
Peak gate power loss	$P_{GM}$	5.0			W	$f \geq 50Hz$ , duty $\leq 10\%$
Average gate power loss	$P_{G(AV)}$	0.5			W	
Junction temperature	$T_j$	-40 to +110			$^{\circ}C$	
Storage temperature	$T_{stg}$	-40 to +125			$^{\circ}C$	

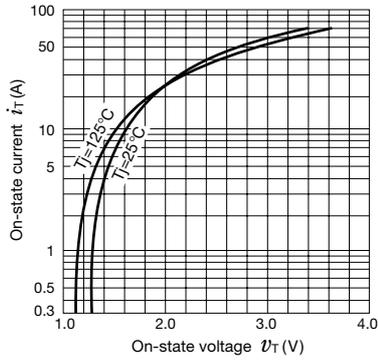
### Electrical Characteristics

Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Off-state current	$I_{DRM}$			1.0	mA	$T_j=125^{\circ}C$ , $V_D=V_{DRM}(V_{RRM})$ , $R_{GK}=1k\Omega$
Reverse current	$I_{RRM}$			1.0	mA	
On-state voltage	$V_{TM}$			1.4	V	$T_c=25^{\circ}C$ , $I_{TM}=5A$
Gate trigger voltage	$V_{GT}$			1	V	$V_D=6V$ , $R_L=10\Omega$ , $T_c=25^{\circ}C$
Gate trigger current	$I_{GT}$			0.1	mA	
Gate non-trigger voltage	$V_{GD}$	0.1			V	$V_D=1/2 \times V_{DRM}$ , $T_j=125^{\circ}C$ , $R_{GK}=1k\Omega$
Holding current	$I_H$		1.0		mA	$R_{GK}=1k\Omega$ , $T_j=25^{\circ}C$
Critical rate-of-rise of off-state voltage	$dv/dt$		20		$V/\mu S$	$V_D=1/2 \times V_{DRM}$ , $T_j=125^{\circ}C$ , $R_{GK}=1k\Omega$ , $C_{GK}=0.033\mu F$
Turn-off time	$t_q$		30		$\mu S$	$T_c=25^{\circ}C$
Thermal resistance	$R_{th}$			3.0	$^{\circ}C/W$	Junction to case

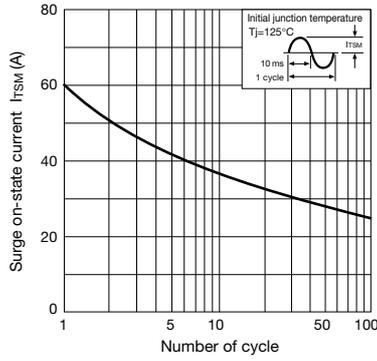


# TF321M-A, TF341M-A, TF361M-A

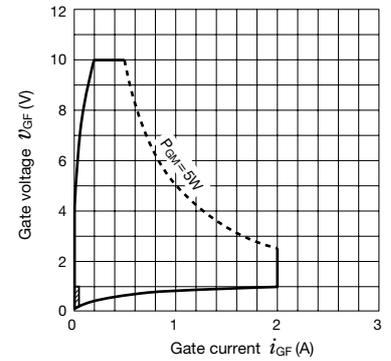
**$V_T - I_T$  Characteristics (max)**



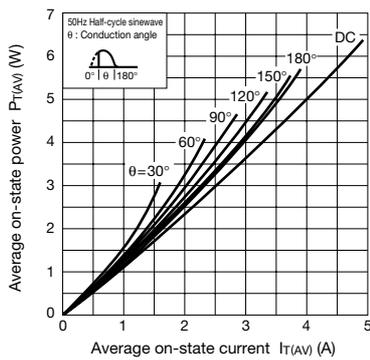
**$I_{TSM}$  Ratings**



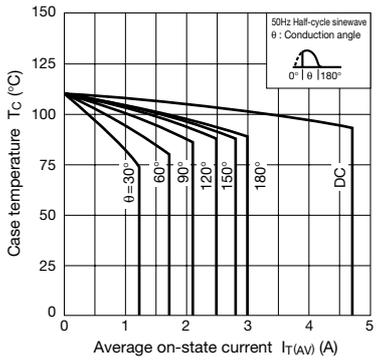
**Gate Characteristics**



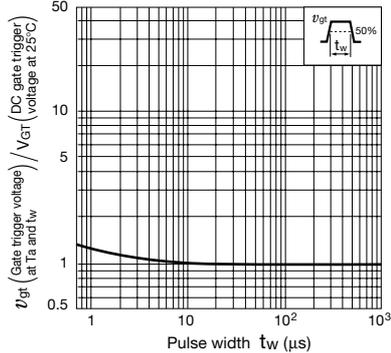
**$I_T(AV) - P_T(AV)$  Characteristics**



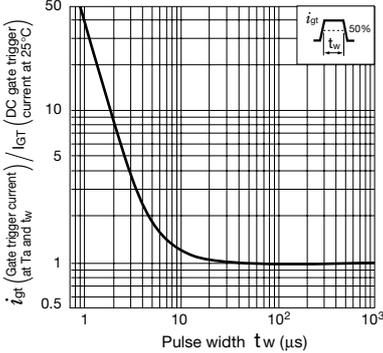
**$I_T(AV) - T_c$  Ratings**



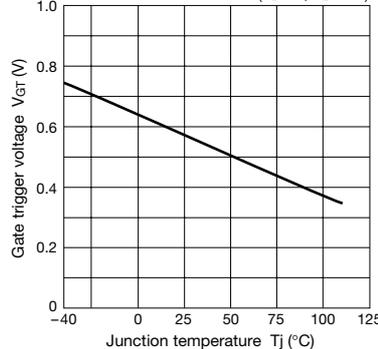
**Pulse trigger temperature Characteristics  $V_{gt}$  (Typical)**



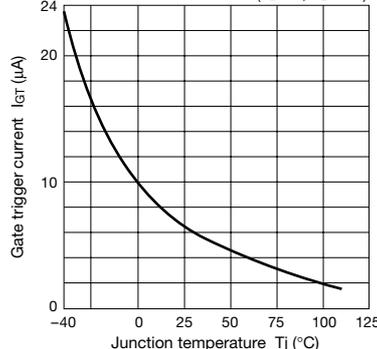
**Pulse trigger temperature Characteristics  $I_{gt}$  (Typical)**



**$V_{GT}$  temperature Characteristics (Typical)**



**$I_{GT}$  temperature Characteristics (Typical)**



**Transient thermal resistance Characteristics (Junction to case)**

